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Application Number	09/352,362
Filing Date	July 13, 1999
First Named Inventor	Shunpei YAMAZAKI et al.
Group Art Unit	2815
Examiner Name	J. Diaz
Attorney Docket Number	0756-1996
Total Number of Pages in This Submission	

ENCLOSURES (check all that apply)

<input type="checkbox"/> Fee Transmittal Form <input checked="" type="checkbox"/> Fee Attached <input checked="" type="checkbox"/> Amendment / Reply <input type="checkbox"/> After Final <input type="checkbox"/> Affidavits/declaration(s) <input checked="" type="checkbox"/> Extension of Time Request <input type="checkbox"/> Express Abandonment Request <input checked="" type="checkbox"/> Information Disclosure Statement <input type="checkbox"/> Certified Copy of Priority Document(s) <input type="checkbox"/> Response to Missing Parts/ Incomplete Application <input type="checkbox"/> Response to Missing Parts under 37 CFR 1.52 or 1.53	<input type="checkbox"/> Assignment Papers (for an Application) <input type="checkbox"/> Drawing(s) <input type="checkbox"/> Declaration and Power of Attorney <input type="checkbox"/> Licensing-related Papers <input type="checkbox"/> Petition <input type="checkbox"/> Petition to Convert to a Provisional Application <input type="checkbox"/> Power of Attorney, Revocation Change of Correspondence Address <input type="checkbox"/> Terminal Disclaimer <input type="checkbox"/> Request for Refund <input type="checkbox"/> CD, Number of CD(s) _____	<input type="checkbox"/> After Allowance Communication to Group <input type="checkbox"/> Appeal Communication to Board of Appeals and Interferences <input type="checkbox"/> Appeal Communication to Group (Appeal Notice, Brief, Reply Brief) <input type="checkbox"/> Proprietary Information <input type="checkbox"/> Status Letter <input checked="" type="checkbox"/> Other Enclosures 1. Change of Correspondence Address Form 2. 3. 4. 5. 6.
Remarks		<input checked="" type="checkbox"/> The Commissioner is hereby authorized to charge any additional fees required or credit any overpayments to Deposit Account No. 50-2280 for the above identified docket number.

SIGNATURE OF APPLICANT, ATTORNEY, OR AGENT

Firm or Individual name	Eric J. Robinson, Reg. No. 38,285 Robinson Intellectual Property Law Office, P.C. PMB 955 21010 Southbank Street Potomac Falls, VA 20165
Signature	
Date	9-20-02

CERTIFICATE OF MAILING

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



Inter Patent Application of

Shunpei YAMAZAKI et al.

Serial No. 09/352,362

Filed: July 13, 1999

For: CRYSTALLINE SEMICONDUCTOR

THIN FILM, METHOD OF FABRICATING

THE SAME, SEMICONDUCTOR DEVICE,

AND METHOD OF FABRICATING THE

SAME

) Art Unit: 2815

) Examiner: J. Diaz

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AMENDMENT

Honorable Commissioner of Patents

Washington, D.C. 20231

Sir:

In response to the Office Action dated April 25, 2002 please amend the above-identified application as follows:

IN THE CLAIMS:

Please cancel claims 25, 26 and 116-122 and amend claims 15, 17, 20, 22, 28 and 30-35 as follows:

15. (Amended) A method of fabricating a semiconductor device comprising:
adding an element for facilitating crystallization of an amorphous
semiconductor thin film to a part or an entire region of the amorphous semiconductor thin
film;

carrying out a first heat treatment to transform the part or the entire region of
the amorphous semiconductor thin film into a crystalline semiconductor thin film;

irradiating a laser light to said crystalline semiconductor thin film; and

carrying out a second heat treatment for the crystalline semiconductor thin
film at 900 to 1200 °C in a reducing atmosphere after the irradiation of said laser light,